Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-931-0437

Inclosure Material:

Metal

**Overall Length:** 

0.405 inches

#### **Overall Diameter:**

0.424 inches

#### **Mounting Facility Quantity:**

1

# Mounting Method:

Threaded stud

### Features Provided:

Hermetically sealed case

### **Overall Width Across Flats:**

Between 0.424 inches and 0.437 inches

# Thread Size:

# 0.190 inches

Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

400.0 reverse voltage, peak

### Current Rating Per Characteristic:

12.00 amperes forward current, average absolute

### Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

### **Thread Series Designator:**

Unf

# Terminal Type And Quantity:

1 threaded stud and 1 tab, solder lug

# **Specification Data:**

81349-mil-s-19500/304 government specification

# Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

Fiig:

A110a0